

PATENT ASSIGNMENT

Electronic Version v1.1
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SUBMISSION TYPE:	NEW ASSIGNMENT												
NATURE OF CONVEYANCE:	ASSIGNMENT												
CONVEYING PARTY DATA													
<table border="1"> <thead> <tr> <th>Name</th> <th>Execution Date</th> </tr> </thead> <tbody> <tr> <td>JUN-RONG CHEN</td> <td>03/28/2013</td> </tr> <tr> <td>HSIU-MEI CHOU</td> <td>03/28/2013</td> </tr> <tr> <td>JHAO-CHENG YE</td> <td>03/28/2013</td> </tr> </tbody> </table>		Name	Execution Date	JUN-RONG CHEN	03/28/2013	HSIU-MEI CHOU	03/28/2013	JHAO-CHENG YE	03/28/2013				
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<table border="1"> <tr> <td>Name:</td> <td>LEXTAR ELECTRONICS CORPORATION</td> </tr> <tr> <td>Street Address:</td> <td>No. 3, Gongye E. 3rd Rd.</td> </tr> <tr> <td>Internal Address:</td> <td>Hsinchu Science Park</td> </tr> <tr> <td>City:</td> <td>Hsinchu</td> </tr> <tr> <td>State/Country:</td> <td>TAIWAN</td> </tr> <tr> <td>Postal Code:</td> <td>30075</td> </tr> </table>		Name:	LEXTAR ELECTRONICS CORPORATION	Street Address:	No. 3, Gongye E. 3rd Rd.	Internal Address:	Hsinchu Science Park	City:	Hsinchu	State/Country:	TAIWAN	Postal Code:	30075
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CORRESPONDENCE DATA													
<p>Fax Number: 7329357122 <i>Correspondence will be sent via US Mail when the fax attempt is unsuccessful.</i></p> <p>Phone: 732-935-7100 Email: lzaveta@mtiplaw.com</p> <p>Correspondent Name: MOSER TABOADA/Raymond R. Moser, Jr. Address Line 1: 1030 Broad Street Address Line 2: Suite 203 Address Line 4: Shrewsbury, NEW JERSEY 07702</p>													
ATTORNEY DOCKET NUMBER:	TLCNP11533												
NAME OF SUBMITTER:	Raymond R. Moser, Jr.												
Signature:	/Raymond R. Moser, Jr./												

PATENT

Date:

07/03/2013

Total Attachments: 2

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ASSIGNMENT

This assignment agreement is applicable to an invention entitled (Invention Title) _____
 EPITAXIAL STRUCTURE AND EPITAXIAL GROWTH METHOD FOR FORMING
 EPITAXIAL LAYER WITH CAVITIES

The PATENT RIGHTS referred to in this agreement are:

- (check one) ☒ a patent application for this invention, executed by the ASSIGNOR(S)
 concurrently with this assignment.
- ☐ U.S. patent application Serial No. _____, filed _____
- ☐ a U.S. patent application based on PCT International Application
 No. _____ filed on (date) _____ (U.S. patent application
 Serial No. _____, if known).
- ☐ U.S. patent No. _____, issued _____.

The PATENT RIGHTS also include all divisions, reissues, continuations and extensions of
 the patents and patent applications identified above.

The PATENT RIGHTS assigned under this agreement are:

- (check one) ☒ U.S. patent rights only.
- ☐ Worldwide patent rights. In this case, the assignee shall have the right to
 claim the benefit of the filing date of any U.S. or foreign patent application
 for this invention.

The ASSIGNOR(S) referred to in this agreement is (or are) the inventor(s) whose signatures
 appear on page 2 of this Assignment and any Supplemental Sheet(s).

The ASSIGNEE referred to in this agreement is:

(Name of Assignee) Lextar Electronics Corporation

(Address) No.3, Gongye E. 3rd Rd., Hsinchu Science Park, Hsinchu 30075, Taiwan,

R.O.C.

The ASSIGNEE is:

- (check one) ☐ An individual.
- ☐ A Partnership.
- ☒ A Corporation of TAIWAN, R.O.C. (specify state or country)
- ☐ (other) _____

The ASSIGNOR(S), in consideration of \$10.00 paid by the ASSIGNEE, and other good and
 valuable consideration, receipt of which is acknowledged, hereby assign(s) the following
 rights to the ASSIGNEE, its successors and assigns:

the full and exclusive right to the invention;

the entire right, title and interest in and to the PATENT RIGHTS;

the right to sue and recover for any past infringement; and

the right to claim priority under 35 USC 119, 35 USC 120, or any other applicable
 provisions, based on any earlier patent applications for this invention.

THIS IS PAGE 2 OF AN ASSIGNMENT FROM THE INVENTOR(S) TO
ASSIGNEE: Lextar Electronics Corporation
INVENTION TITLE: EPITAXIAL STRUCTURE AND EPITAXIAL GROWTH
METHOD FOR FORMING EPITAXIAL LAYER WITH CAVITIES

As to all U.S. patent applications assigned under this agreement, the ASSIGNOR(S) hereby authorize(s) and request(s) the Commissioner of Patents and Trademark to issue all Letters Patent to the ASSIGNEE as the assignee of the entire right, title and interest, for the sole use and enjoyment of said ASSIGNEE, its successors and assigns.

Further, the ASSIGNOR(S) agree(s) to communicate to said ASSIGNEE, or its representatives, any fact known to the ASSIGNOR(S) with respect to said invention, and testify in any legal proceeding, sign all lawful papers, execute all divisional, continuation, substitute, renewal, reexamination and reissue applications, execute all necessary assignment papers to cause and all Letter Patent to be issued to said ASSIGNEE, make all rightful oaths and generally do everything necessary or desirable to aid said ASSIGNEE, its successors and assigns, to obtain and enforce proper protection for said invention.

The ASSIGNOR(S) authorize(s) the attorneys and agents who have the power of attorney in this application to check any appropriate boxes and to insert the Serial Number and filing date in this document after it has been executed.

<u>Jun-Rong CHEN</u>	<u>Jun-Rong Chen</u>	<u>2013.3.28.</u>
Name of sole or first inventor	Signature	Date
<u>Hsiu-Mei CHOU</u>	<u>Hsiu-Mei Chou</u>	<u>2013/03/28</u>
Name of second inventor, if any	Signature	Date
<u>Jhao-Cheng YE</u>	<u>Jhao - Cheng YE</u>	<u>2013.3.28.</u>
Name of third inventor, if any	Signature	Date